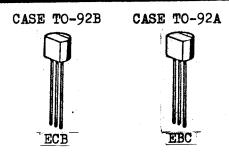


## 2N 3702 through 2N 3706 MPS 3702 through MPS 3706

PNP . NPN SILICON GENERAL PURPOSE AF TRANSISTORS

THE ABOVE TYPES ARE SILICON PLANAR EPITAXIAL TRANSISTORS FOR GENERAL PURPOSE AF MEDIUM POWER APPLICATIONS. THE 2N3702 SERIES ARE SUPPLIED IN CASE TO-92B. THE MPS3702 SERIES ARE SUPPLIED IN CASE TO-92A.



		(PNP)	(PNP)	(NPN)	(NPN)			
ABSOLUTE MAXIMUM RATINGS		2N/MPS3702	2N/MPS3703	2N/MPS3704 2N/MPS3705	2N/MPS3706			
Collector-Base Voltage	$v_{CBO}$	40 <b>v</b>	50 <b>v</b>	50 <b>v</b>	40 <b>V</b>			
Collector-Emitter Voltage	$v_{CEO}$	25 <b>v</b>	30 <b>v</b>	30 <b>v</b>	20 <b>V</b>			
Emitter-Base Voltage	$v_{\rm EBO}$	5 <b>v</b>	5 <b>v</b>	5 <b>v</b>	5 <b>v</b>			
Collector Current	IC	0.2A	0.2A	0.84	0.8A			
Collector Peak Current	ICM	0.6A	0.6A	Magazi *				
Total Power Dissipation (TC ≤ 25°C)	Ptot		1	W				
(TA ≤ 25°C)			360mW					

Operating Junction & Storage Tj, Tstg Temperature

-55 to 150°C

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

CLECTRICAL CHARACTERISTICS ("A-2) C	anii coo	, 0110 T W	200 211	Jucar			
PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CON	ITIONS
Collector-Base Breakdown Voltage	вусво	1			٧	Ic=0.lmA	IE=0
Collector-Emitter Breakdown Voltage	LVCEO *	Note	1		٧	Ic=10mA	IBTO
Emitter-Base Breakdown Voltage	BVEBO	↓			٧	IE=0.lmA	Ic=0
Collector Cutoff Current	ICBO			100	nA	ACB=50A	IE=0
Emitter Cutoff Current	IEBO			100	nA	VEB=3V	IC=0
Collector-Emitter Saturation Voltage 2N/MPS3702,3 2N/MPS3704 2N/MPS3705 2N/MPS3706	VCE(sat)	) <del>*</del> 	0.1 0.12 0.15 0.15	0.8	v v v	IC=50mA IC=100mA IC=100mA IC=100mA	IB=5mA IB=5mA
Base-Emitter Voltage 2N/MPS3702,3 2N/MPS3704,5,6	V <sub>BE</sub> *	0.6 0.5	0.78		v v	Ic=50mA Ic=100mA	- ,
D.C. Current Gain 2N/MPS3702 2N/MPS3703 2N/MPS3704	HFE *	60 30 100		300 150 300		Ic=50mA Ic=50mA Ic=50mA	VCE=5V VCE=5V VCE=2V

For p-n-p devices, voltage and current values are negative.

MICRO ELECTRONICS LTD.

38 HUNG TO ROAD, KWUN TONG, HONG KONG. TELEX 43510 KWUN TONG P. O. BOX69477 CABLE ADDRESS TELEPHONE:- 3-430181-6 3-893363. MICROTRON"

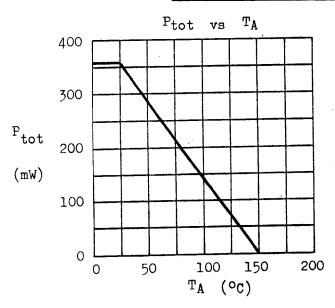
FAX: 3-410321

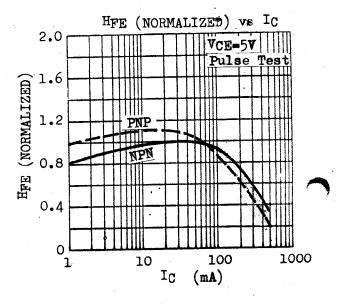
\_ \_ \_ Continued - - -

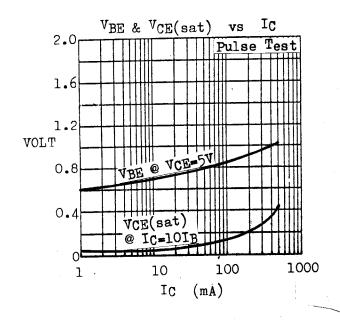
PAR	SYMBOL	MIN	TYP	MAX	UNIT	TEST CON	DITIONS	
D.C. Current Gain	2 <b>n/</b> MPS3705 2 <b>n/</b> MPS3706	HFE *	50 30		150 600	-	Ic=50mA Ic=50mA	ACE=5A
Current Gain-Bandwidth Product 2N/MPS3702,3 2N/MPS3704,5,6		fŢ	100			MH2 MH2	IC=50mA IC=50mA	VCE=5V VCE=2V
Collector-Base Capac	citance 2N/MPS3702,3 2N/MPS3704,5,6	Cob		5 4	12 12	pF pF	VCB=10V f=1MHz	IE=O

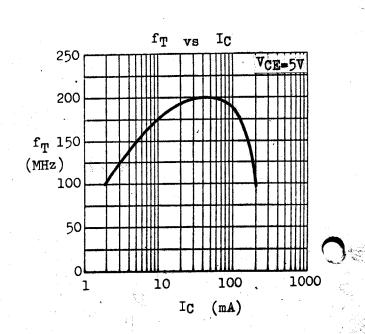
Note 1: equal to the values of absolute maximum ratings.

## TYPICAL CHARACTERISTICS (TA=25°C unless otherwise noted)





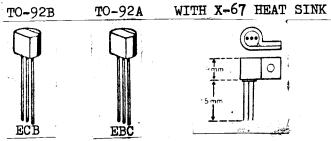




<sup>\*</sup> Pulse Test: Pulse Width=0.3mS, Duty Cycle=1%

## TRANSISTORS EQUIVALENT TO 2N/MPS3702 FAMILY

THE FOLLOWING TRANSISTORS, WHICH ARE CLOSELY EQUIVALENT TO THE 2N/MPS3702 FAMILY, ARE ALSO AVAILABLE.



g p	ECTETC ATT	ONS AT TA=	25 <b>0</b> C	For page de	vices, voltage and current	CB EBC		
	,	CASE	LVCEO		ICBO @ VCB		VCE(sat) @ IC/IB	fT @ IC
TYPE	POLARITY	(Ptot)	(V)	(v)	(V) (Aμ)	(mA) (V)	(V) (mA)(mA)	(MHz)(mA)
			min	min	max	min-max	max	min
2 <b>N3</b> 402			25	5	0.1 @ 25	75 <b>-</b> 225 @ 2/4 <b>.</b> 5	0.3 @ 50/3	and the same of th
2N 3402		TO-92B	25	5	0.1 @ 25	180-540 @ 2/4.5	0.3 @ 50/3	
2N3404	NPN	with X-67 Heat Sink		5	0.1 @ 50	75-225 @ 2/4.5	0.3 @ 50/3	
2N3405		(560mW)	50	. 5	0.1 @ 50	180-540 @ 2/4.5	0.3 @ 50/3	
2N4425		:	40	5	*0.03@ 40	<b>18</b> 0-540 @ 2/4.5	0.3 @ 50/3	
2N3414			25	5	0.1 @ 25	75 <b>-</b> 225 @ 2/4.5	0.3 @ 50/3	·
2 <b>N3</b> 415	NPN	TO-92B	2-5	5	0.1 @ 25	180-540 @ 2/4,5	0.3 @ 50/3	
2 <b>N3416</b>		(360mW)	50	5	0.1 @ 50	75 <b>-</b> 225 @ 2/4•5	0,3 @ 50/3	
2N3417			50	5	0.1 @ 50	180-540 @ 2/4.5	0.3 @ 50/3	
~2N4424			- 40	5	<b>*</b> 0.03@ 40	180-540 @ 2/4.5	0.3 @ 50/3	
2N5220	NPN		15	3	0.1 @ 10	25- @ 10/10 30-600 @ 50/10	0.5 @ 150/15	100 @ 20
2N5221	PNP	TO-92A	15	3	0.1 @ 10	25- @ 10/10 30-600 @ 50/10	0.5 @ 150/15	100 @ 20
2N5225	NPN	(350mW)	25	4	0.3 @ 15	25- @ 10/10 30-600 @ 50/10	0.8 @ 100/10	50 <b>@ 20</b>
2N5226	PNP		25	4	0.3 @.15	25- @ 10/10 30-600 @ 50/10	0.8 @ 100/10	50 @ 20
2N5354	PNP		25	4	<b>*</b> 0.1 @ 25	40-120 @ 50/1 20- @ 300/5		
2 <b>N</b> 5355	PNP	TO-92B (3 <u>6</u> 0mW)	25	4	<b>*</b> 0 <b>.</b> 1 @ 25	100-300 @ 50/1 40- @ 300/5	0.25 @ 50/2.5 1.0 @ 300/30	
2N5356	PNP		25	4	<b>*</b> 0.1 @ 25	250 <b>-</b> 500 @ 50/1 75 <b>-</b> @ <b>3</b> 00/5		
2N5365	PNP		40	4	*0.1 @ 40	40-120 @ 50/1 20- @ <b>300/</b> 5		
T <sup>2</sup> N5366	PNP	TO-92B (360mW)	40	4.	*0.1 @ 40	100-300 @ 50/1 40- @ 300/5	0.25 @ 50/2.5 1.0 @ 300/30	
2N5367	PNP	n	40	4	<b>*</b> 0.1 <b>@</b> 40	250-500 <b>©</b> 50/1 75 <b>©</b> 300/5		

TYPE	POLARITY	CASE (Ptot)	LVCEO	BVEBO	I <sub>CES</sub> (μΑ)	(v) @ v <sub>ce</sub>	1	C/VCE	VCE(sat) (V)		fT @ IC
			min	min	max		min-max		max		min
2N5418	NPN		25	4	0.1	@ 25 	40 <b>-</b> 120 20-	@ 50/1 @ 300/5			
2N5419	NPN	TO-92B (400mW)	25	4	0.1	@ 25	100-300 40-	@ 50/1 @ 300/5	0.25 @ 1.0 @	50/2 <b>.</b> 5 300/30	
2N5420	NPN		25	4	0.1	@ 25	250 <b>-</b> 500 75 <b>-</b>	@ 50/1 @ 300/5			
2N5447	PNP										
2N5448	PNP				<b>m</b> ∧	007 +		Mb ÷	im oloain	ri an l	
2N5449	NPN		c]	naract	eristi	.cs ar	e exactl	y identi	ir electr cal to	TOST	
2N5450	NPN		2]	N) (UZ,	<b>),</b> 4,	) <b>,</b> 0	respect	TAGTA			
2N5451	NPN									ing Signatura Signatura	

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